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Which triatomic monohalosilylenes, monohalogermylenes, and monohalostannylenes (HMX) fluoresce or phosphoresce and why? An ab initio investigation

This is the final peer-reviewed author's accepted manuscript (postprint) of the following publication:

Published Version:

Tarroni Riccardo, Clouthier Dennis J. (2022). Which triatomic monohalosilylenes, monohalogermylenes, and monohalostannylenes (HMX) fluoresce or phosphoresce and why? An ab initio investigation. THE JOURNAL OF CHEMICAL PHYSICS, 156, 1-13 [10.1063/5.0083068].

Availability:

This version is available at: https://hdl.handle.net/11585/871614 since: 2024-09-09

Published:

DOI: http://doi.org/10.1063/5.0083068

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ABSTRACT

The possibilities of emission from the \widetilde{A}^IA'' and \widetilde{a}^3A'' excited states of the triatomic halosilylenes, halogermylenes, and halostannylenes (HMX, M=Si, Ge, Sn, X = F, Cl, Br and I) have been explored in a series of extensive *ab initio* calculations. The triplet states are found to have deep bonding wells supporting an extensive manifold of vibrational levels which could give rise to observable triplet-singlet phosphorescence. The \widetilde{a} - \widetilde{X} band systems of the halosilylenes are calculated to occur at the red edge of the visible and are likely to be very weak. In contrast, the HGeX and HSnX triplet-singlet spectra are shifted $1000 - 2000 \text{ cm}^{-1}$ to the higher energy and are expected to be significantly stronger due to increased spin-orbit coupling, making the spectra viable targets for experimental investigations. The \widetilde{A} - \widetilde{X} fluorescence is found to be limited by the possibility of HMX $(\widetilde{A}^IA'') \rightarrow H(^2S) + MX(^2\Pi)$ dissociation in the excited state leading to the expectation that HGeF is unlikely to be detectable by laser-induced fluorescence (LIF) spectroscopy. The HSiX and HGeX species with known LIF spectra are found to have deeper \widetilde{A} state bonding wells and minimal or no calculated barriers to dissociation. It is generally found that the intensity in their LIF spectra tails off due to a diminution of vibrational overlap rather than the abrupt opening of a dissociation channel.

Few of the HSnX species are known experimentally. HSnF and DSnF are found to dissociate very low down in the \widetilde{A} state vibrational manifold and are predicted to be unobservable by LIF spectroscopy. The LIF spectrum of HSnCl is expected to consist of only 1 or 2 bands, with slightly more activity for DSnCl, precisely as has recently been found experimentally. HSnBr and DSnBr have deeper \widetilde{A} state bonding wells and their LIF spectra are thus likely to be more extensive. Although HSnI/DSnI are calculated to have deep bonding wells with respect to the H + MX dissociation, predictions are complicated by the existence of a global small bond angle minimum and the opening of a second SnH + I dissociation channel.

I. INTRODUCTION

Over the last two decades, the Clouthier group have studied the electronic spectra of the halosilylenes and halogermylenes (HSiX; HGeX, X = F, Cl, Br, I) by laser induced fluorescence (LIF) in supersonic expansions. The \widetilde{A} - \widetilde{X} LIF and emission spectra of HSiF, ¹⁻³ HSiCl, ^{4.5} HSiBr, ^{5.6} HSiI, ^{7.8} HGeCl, ^{9.10} HGeBr ¹¹ and HGeI ^{11,12} and their deuterated isotopologues have been recorded and the ground and excited state molecular structures determined. Recently, we have extended these investigations to the corresponding halostannylenes, successfully observing the LIF spectra of HSnCl and DSnCl. ¹³ In some cases, we have been unable to observe fluorescence under conditions which should have produced the reactive intermediate (HGeF) or the LIF spectra were only detectable by excitation of the lowest few vibronic levels in the excited state, particularly for the stannylenes. In SnH2 and SnD2, it seemed clear from fluorescence lifetime and hole burning measurements that upper state dissociation was the cause of the breaking off of the fluorescence. ¹⁴ Since these are all small triatomic molecules, it is unlikely that other nonradiative processes would occur with appreciable efficiency. We speculated that *ab initio* theory might be employed to predict the fluorescence properties of any particular species by studying the excited state potential relative to the expected dissociation products. In this work, we report the results of a comprehensive theoretical study and compare the predictions with the available experimental data.

There have been a substantial number of theoretical papers studying various aspects of the properties of the HMX (M=Si, Ge, Sn; X=F, Cl, Br, I) molecules. Here, we very briefly review the most recent contributions relevant to the present work. Mok and coworkers have used *ab initio* theory and Franck-Condon simulations to study the molecular structures and $\tilde{A} - \tilde{X}$ absorption and emission spectra of HSiF/DSiF, ¹⁵ HSiCl/DSiCl ¹⁶ and HGeCl/DGeCl, ¹⁷ including vibrational anharmonicity. Their predicted geometries, vibrational frequencies and spectra were in generally good accord with experiment. Contemporaneously, Lin *et al* published similar studies of the ground and first excited singlet states of HGeCl/DGeCl, ¹⁸ HGeBr/DGeBr¹⁹ and HSiCl/DSiCl. ²⁰ They emphasized the importance of *3d* orbitals in the Ge containing species and found very good agreement between theory and experiment for the molecular geometries, vibrational frequencies and simulations of spectra.

In 2011, Ehara et al.²¹ used the analytical energy gradients of the direct symmetry-adapted cluster–configuration interaction method to predict the absorption and emission spectra of the HSiF/DsiF and HsiCl/DsiCl species. Good agreement was found in all cases between theory and experiment, reinforcing once again the viability of using *ab initio* methods to predict the ground and excited singlet state properties of the HMX species. Finally, in two papers, Bundhun *et al.* used density functional theory (DFT) methods to predict the ground and excited triplet state geometries and energies of a variety of HMX species including HGeX²² and HSnX.²³ The reader is referred to the original references for a more complete background to the various diverse theoretical studies of HMX molecules. We are not aware of any theoretical studies of the HMX molecules that directly address the role of excited state dissociation processes in the spectroscopy.

II. COMPUTATIONAL METHODS

The majority of the calculations were undertaken with the Molpro2010 program²⁴ with limited contributions from the Orca code.²⁵ For light atoms the Dunning correlation consistent basis sets aug-cc-pVQZ (H, F) and aug-cc-pV(Q+d)Z (Si,Cl) were employed while for the heavier Ge, Br, Sn and I atoms, effective core potentials embodied in the aug-cc-pVQZ-PP basis were utilized.²⁶⁻²⁸ For the drawing of the plots, the triple-zeta homologues of the same bases were used. Finally, some Density Functional Theory (DFT) calculations with the Orca code have also been performed using the Karlsruhe def2-QZVPPD basis.²⁹

Molecular energies were calculated with the Complete Active Space Self-Consistent Field (CASSCF) method^{30,31} followed by Internally Contracted Multireference Configuration Interaction^{32,33} plus Davidson correction with relaxed reference^{34,35} (ICMRCI+Q). All the calculations were performed in C_s symmetry. The HMX molecules all have 12 valence electrons and the active space can be formed starting from the ns and np orbitals of M and X and the 1s, 2s, 2p orbitals of H. These form an active set of 13 orbitals (10a and 3a), which unfortunately proved to be too large for practical ICMRCI computations. The configuration space was then reduced by keeping the lowest valence a orbital always doubly occupied and removing the two highest a orbitals from the active space. The final active space used for the CASSCF state-averaged computations and subsequent

ICMRCI computations was then formed by 10 electrons distributed in 10 (7a' and 3a'') orbitals. The state averaged CASSCF(10,10) molecular orbitals were optimized for the three lowest electronic states of HMX: \widetilde{X}^1A' , \widetilde{a}^3A'' , and \widetilde{A}^1A'' .

The \widetilde{X}^IA' , \widetilde{a}^3A'' and \widetilde{A}^IA'' surfaces were mapped by means of one-dimensional plots along the HMX bending, the MH stretching and MX stretching coordinates, using the CASSCF(10,10)/ICMRCI+Q/aug-cc-pVQZ method, keeping the remaining two inactive coordinates fixed. The stationary points of the potential energy surfaces (minima for the \widetilde{X}^IA' and \widetilde{a}^3A'' states, minimum and saddle point for the \widetilde{A}^IA'' state) for all 12 molecular species were located at the CASSCF(10,10)/ICMRCI+Q/aug-cc-pVQZ level using finite derivative methods. A grid of $5\times5\times5$ displaced geometries was generated around the stationary points, with a spacing of 0.05 bohr for bond distances and 0.05 rad for bond angles. Single point CASSCF(10,10)/ICMRCI+Q/aug-cc-pVQZ energies were evaluated at the displaced geometries and subsequently fitted to a quartic polynomial by means of the SURFIT program. The quartic polynomial was then converted to a quartic force field in internal coordinates, which was finally used to calculate the spectroscopic parameters and anharmonic vibrational levels using second order perturbation theory. Equilibrium geometries, fundamental frequencies and electronic excitation energies as well as other spectroscopic information (quartic force fields, rotational constants, centrifugal distortion constants, rotation-vibration coupling constants and anharmonic vibrational constants) have been obtained for all 12 HMX molecules.

For the saddle point of the $\widetilde{A}^I A''$ states, a smaller grid of $3\times3\times3$ points (with the same spacings as before) was generated and the energy fitted to a quadratic polynomial with SURFIT. This surface was used to calculate the harmonic frequencies needed to estimate the zero-point energy of the transition state.

The CASSCF(10,10) frontier orbitals (HOMO-1,HOMO,LUMO,LUMO+1) of the 12 HMX molecules were also plotted by means of the appropriate Molpro utility interfaced to the gOpenMol graphic program.³⁸ The geometries chosen to plot the orbitals were the same used as reference to map the potential energy surfaces.

The lowest dissociation energies of HMX were estimated by computing separately the energies of the fragments at three different level of theory: a) the density functional theory (DFT) with the Becke three parameter hybrid density functional³⁹ and the Lee, Yang, and Parr correlation functional⁴⁰ (B3LYP), and the def2-QZVPPD²⁹ basis set; b) the Complete Active Space Perturbation Theory^{41,42} (CASPT2) method and c) the ICMRCI+Q technique, both b) and c) with the set of augmented quadruple-zeta bases described above and all valence electrons correlated. Basis set superposition and size consistency errors were not considered, and spin-orbit splittings and vibrational zero point energies of the diatomic products were neglected. The dissociation energies were also calculated using the supermolecule approach,⁴³ with the atomic and diatomic fragments placed at a collinear geometry separated by 10 Å, and optimizing the geometries of the diatomic fragments.

III. RESULTS

The most relevant parameters for our subsequent discussion of the fluorescent properties of all the HMX molecules are summarized in Tables II – IV of the manuscript. In order to explain the range and depth of the calculations that were done on each of the HMX molecules, we have elected to present the detailed results for one species and relegate the remainder to the Supplementary Material. We have chosen the molecule HGeF as our prototypical molecule, as it has some of the attributes of both the silicon and tin species and, despite considerable effort, it has never been detected by LIF methods in the gas phase.⁹

A. The electronic states of the HMX molecules

All the HMX molecules have 12 valence electrons. The four outermost electrons give the ground state configuration:

$$\widetilde{X}^{l}A'$$
: ... $(a''$ Homo-1 $)^{2}(a'$ Homo $)^{2}(a''$ Lumo $)^{0}(a'$ Lumo+1 $)^{0}$

As an example, the four frontier orbitals of HGeF are shown in Fig. 1, with similar plots for the other HMX species shown in the Supplementary Material. Both the a'_{HOMO} and the a''_{LUMO} are localized on the Ge atom. The former is essentially a lone-pair non-bonding sp^2 hybrid orbital while the latter is an empty p orbital. Excitation from the doubly occupied a'_{HOMO} to the unoccupied a''_{LUMO} orbital gives either a triplet state:

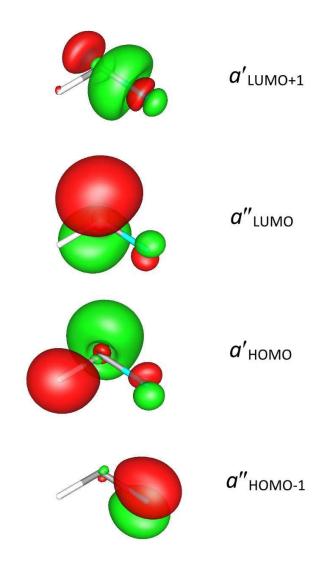


Figure 1 State-averaged CASSCF/aug-cc-pV(T+d)Z frontier molecular orbitals of HGeF. The orbitals are calculated at $r_{GeF}=1.75$ Å, $r_{GeH}=1.62$ Å, $\theta_{HGeF}=100^{\circ}$.

$$\tilde{a}^{3}A''$$
: ... $(a''_{\text{HOMO-1}})^{2}(a'_{\text{HOMO}})^{\alpha}(a''_{\text{LUMO}})^{\alpha}(a'_{\text{LUMO+1}})^{0}$

or a singlet state with diradical character

$$\tilde{A}^{I}A''$$
: ... $(a''\text{HOMO-1})^{2}(a'\text{HOMO})^{\alpha}(a''\text{LUMO})^{\beta}(a'\text{LUMO+1})^{0}$

Other excited states with A 'symmetry can be produced by excitation of an electron from the doubly occupied a'_{HOMO} to the unoccupied $a'_{\text{LUMO+1}}$ orbital:

$$3^{1}A' \dots (a''\text{homo-1})^{2}(a'\text{homo})^{\alpha}(a''\text{lumo})^{0}(a'\text{lumo+1})^{\beta}$$

$$2^{3}A'$$
: ... $(a''$ homo-1 $)^{2}(a'$ homo $)^{\alpha}(a''$ lumo $)^{0}(a'$ lumo+1 $)^{\alpha}$

Potential energy curves for the low-lying electronic states of HGeF as functions of the geometric parameters are shown in Fig. 2, panels A-C. It is evident (panel A) that, for the \tilde{A}^IA'' state along the r_{GeH} coordinate, a small barrier to dissociation is present. Such a barrier is not present either in the ground state or in the first triplet state. Moreover, the ground \tilde{X}^IA' state was found to correlate at linear geometries with a $^1\Sigma^+$ state while the \tilde{A}^IA'' and $3^IA'$ states correlate with a $^1\Pi$ state. On the other hand, the \tilde{a}^3A'' and $2^3A'$ triplet states correlate at linearity with a $^3\Pi$ state (panel C). This behavior is quite different from that of the HCX (X = F,Cl,Br,I) halocarbenes⁴⁴, for which the \tilde{X}^IA' and \tilde{A}^IA'' states correlate at linear geometries with a $^1\Delta$ state.

All the HMX molecules generate similar plots as documented in the Supplementary Material. It is evident that the strongly bound \tilde{A}^IA' and \tilde{a}^3A'' states do not show any barrier to dissociation, while the more weakly bound \tilde{A}^IA'' states show a small barrier whose height decreases on passing from F-containing molecules to Cl-containing molecules, becoming very small or negligible for Br- and I-containing molecules. This behavior is common to all HMX, including M = carbon.

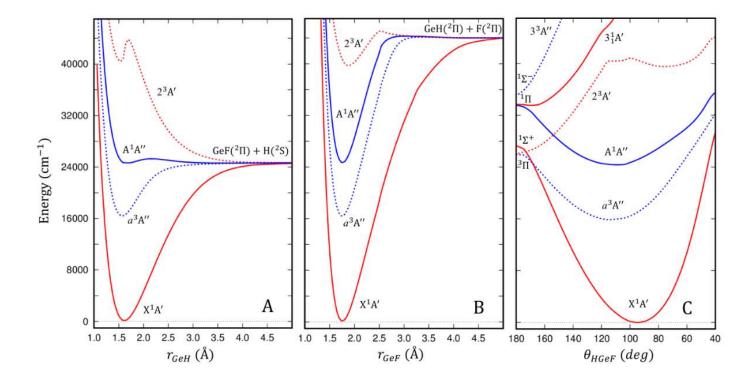


Figure 2. Low-lying singlet (solid lines) and triplet (dashed lines) potential energy curves of HGeF. Red lines correspond to A' states and blue lines to A'' states. Panel A: $r_{GeF}=1.75$ Å, $\theta_{HGeF}=100^\circ$; panel B: $r_{GeH}=1.62$ Å, $\theta_{HGeF}=100^\circ$; panel C: $r_{GeF}=1.75$ Å, $r_{GeH}=1.62$ Å; All energies are relative to the minimum of the X^1A' state

B. Dissociation products

The HMX triatomic molecules can dissociate into three different ground state atomic-diatomic products.

These are

a)
$$MX(^{2}\Pi) + H(^{2}S)$$

b) $MH(^{2}\Pi) + X(^{2}P)$
c) $HX(^{1}\Sigma^{+}) + M(^{3}P)$ (1)

Channels a) and b) are both accessible from all three \tilde{X}^IA' , \tilde{a}^3A'' and \tilde{A}^IA'' electronic states while spin restrictions limit channel c) to the \tilde{a}^3A'' state. The relative energies, with $MX(^2\Pi) + H(^2S)$ taken as reference, of channels b) and c) have been calculated at three levels of theory, B3LYP/def2—QZVPPD, CASPT2/aug-cc-pVQZ and ICMRCI+Q/aug-cc-pVQZ. These relative energies correspond to the differences between the dissociation energies of the MX and the MH diatomic molecules and to the differences between the dissociation energies of MX and HX diatomic molecules, respectively. The results are summarized in Table I and compared with the values obtained from tabulated experimental dissociation energies.⁴⁸ For the ICMRCI+Q method, a second value enclosed in square parentheses is also reported in Table I,. This quantity was evaluated as the difference in the dissociation energies reported in Tables II-IV, which in turn were obtained with the supermolecule approach. The various methods give relative energies which can differ by as much as ~7000 cm⁻¹ (~ 80 kJ/mol) reflecting the intrinsic difficulty of obtaining accurate thermochemical predictions by means of ab initio methods. By comparing the theoretical and experimental values, it is evident that none of the four methods is noticeably better than the others. However, the CASPT2 and supermolecule ICMRCI values are generally closest to each other. On the other hand, the experimental values themselves are subject to large errors, making comparisons quite awkward. Despite these difficulties, some general trends can be recognized. First, the $HX(^{1}\Sigma^{+}) + M(^{3}P)$ dissociation is always the energetically most favorable, but only the \tilde{a}^3A'' state of HMX can dissociate in this way. The \widetilde{X}^lA' and \widetilde{A}^lA'' states, having different spin multiplicity, can access this dissociation channel only through an intersystem crossing to the \tilde{a}^3A'' state. Second, the $MH(^2\Pi) + X(^2P)$ halogen loss dissociation

Table I. Calculated lowest dissociative channels of the HMX species. All energies (in cm⁻¹) are relative to the $MX(^2\Pi) + H(^2S)$ channel. Calculations are performed at the B3LYP/def2-QZVPPD (upper value) CASPT2/aug-cc-pVQZ (middle value) and ICMRCI+Q/aug-cc-pVQZ (lowest value) levels. The value enclosed in square parentheses on the same line of ICMRCI+Q is evaluated from the dissociation energies reported in Tables II-IV. The values reported in parentheses for the $HX(^1\Sigma^+) + M(^3P)$ channels are the difference between the experimental MX and HX diatomic dissociation energies. The values reported in parentheses for the $MH(^2\Pi) + X(^2P)$ channels are the difference between the experimental MX and MH diatomic dissociation energies. All experimental dissociation energies taken from ref. 48. See text for details.

		F	Cl	Br	I
HSiX	$HX(^{1}\Sigma^{+}) + Si(^{3}P)$	693	-1707	-1481	-1687
		-617	-1896	-918	-372
		-1703	-3474	-2246	-1560
		(600 ± 1400)	(-1230±530)	(-670±720)	(-4610±710)
	$SiH(^2\Pi) + X(^2P)$	23178	7233	4530	-330
		23617	10234	5581	836
		21133 [23571]	8131 [9248]	3633 [4786]	-1134 [70]
		(23700±1600)	(10320 ± 690)	(5430±860)	(-4200±860)
HGeX	$HX(^{1}\Sigma^{+}) + Ge(^{3}P)$	-5478	-4122	-3102	-2653
		-6388	-4509	-2817	-1707
		-7275	-5986	-4139	-2913
		(-3900±1100)	(-3400±800)	(-1600±690)	(-2500±2100)
	$GeH(^2\Pi) + X(^2P)$	18894	8332	4796	591
		19797	9571	5622	1451
		17873 [22678]	7732 [9288]	3853 [5356]	-374 [1366]
		(21700±1500)	(10700 ± 1200)	(7000±1100)	(400±2500)
HSnX	$HX(^{1}\Sigma^{+}) + Sn(^{3}P)$	-8038	-5325	-3964	-3300
		-9272	-5818	-4344	-3284
		-10286	-7303	-5734	-4682
		(-7800±670)	(-6800±670)	(-2400±1100)	(-5290±260)
	$SnH(^2\Pi) + X(^2P)$	24312	9210	6014	2024
		18863	10113	6056	1825
		16669 [19016]	8422 [11571]	4265 [7613]	-137 [1908]
		(17700±2100)	(7200±2100)	(6100±2500)	(-2400±1700)

generally requires more energy than the $MX(^2\Pi) + H(^2S)$ hydrogen loss dissociation. However, the difference decreases rapidly going from F to Cl to Br, and for HMI compounds in the \tilde{A} $^IA''$ state, the halogen loss dissociation may be competitive with hydrogen loss. This fact and the presence of a secondary minimum in the \tilde{A} $^IA''$ potential energy surfaces make predictions for the HMI compounds particularly difficult.

C. Spectroscopic properties of HMX ground and lowest excited states

Tables II -IV summarize the major results of this study, with each cell containing the calculated value and an experimental value (where available) directly below in parentheses. First the calculated geometric parameters of each molecule are tabulated along with any available experimentally determined values. Since the $\tilde{a}^3A'\tilde{A}'\tilde{A}'$ transitions have yet to be observed for any of the HMX molecules, there are no experimental data available for the triplet states. The *ab initio* values are equilibrium values (r_e) whereas the experimental quantities are usually zero-point (r_θ) values, which would be expected to be slightly larger. HGeF and DGeF and many of the HSnX species have not been detected spectroscopically so there is no experimental information on their geometries, vibrational frequencies or electronic excited states. For each species we also report the geometry and energy of the transition state (\tilde{A} r_s) connecting the \tilde{A} state minimum to the dissociation limit and the energies of the dissociation limits for the MX + H and MH + X channels. The latter, calculated at the same level as the equilibrium energies, were computed within the supermolecule approach.

In column 6 ("Energy") the calculated T_e energies are reported relative to the minimum of the \widetilde{X} state. The next entries in the Tables are the vibrational *fundamentals* with $v_1 = MH$ stretch, $v_2 = bend$ and $v_3 = MX$ stretch. These have been calculated by determining the harmonic vibrational frequencies and anharmonicities and combining them with the relationships:

$$v_1 = \omega_1 + 2x_{11} + \frac{1}{2}(x_{12} + x_{13}) \tag{2}$$

$$v_2 = \omega_2 + 2x_{22} + \frac{1}{2}(x_{21} + x_{23}) \tag{3}$$

Table II. Spectroscopic parameters for the \widetilde{X} , \widetilde{a} and \widetilde{A} states of HSiX, and DSiX (X = F, Cl, Br, I). Experimental data (in parentheses) from

refs. 1-8. See the text for other details.

											,																			_
erties	v_2'	DSiX			9	(9)						12	(10)							15	(8)						>10 (4)	·		
n Prope	${\rm Max}\ \nu_2'$	HSiX			4	(4)						6	(4)							10	(5)						>6 (4)	· ·		
Predicted Emission Properties	nergy	DSiX			3223	(2792)						5050	(4106)							5642	(4307)						6964 (2650)	,		
Predicte	Max energy (cm ⁻¹)	HSiX			2945	(2398)						4732	(3761)							5317	(4972)						6616 (3115)			
	Energy (cm ⁻¹)	T_{0}	1	13652	23493	(23339)	26716			1	11996	20906	(20773)	25956			1		11706	20064	(19954)	25706			ı	11017	18534 (18303)	25498		
iX	cm ⁻¹)	1/3	833 (840)	834	823	(854)	831			515 (518)	554	535	(543)	521			410	(408)	433	417	(434)	415			349 (345)	371	343 (325)	343 b		
DSiX	entals (1/2	(638)	452	395	(425)	146			584 (592)	465	413	(409)	120			550	(562)	441	385	(376)	107			514 (528)	413	359 (368)	0		
	Fundar	V_l	1413 (1401)	1518	1231	(1174)	280i			1423 (1434)	1503	1308	(1301)	-243 <i>i</i>			1406	(1440)	1477	1308	(1326)	179 <i>i</i>			1402 (1443)	1469	1336	0		
	Energy (cm ⁻¹)	T_{θ}	-	13634	23406	(23260)	26351			ı	11989	20852	(20718)	25584			•		11698	20014	(19903)	25331			ı	11010	18490 (18259)	25106		
ΙX	Energy Fundamentals (cm ⁻¹) Energy Fundamentals (cm ⁻¹)	1/3	808)	850	835	(857)	831			515 (523)	548	532	(532)	521			410	(412)	435	417	(417)	416			349 (350)	370	344 (336)	344 b		
HSiX	entals (1/2	885 (860)	611	536	(558)	194			801 (806)	641	564	(564)	164			761	(772)	603	529	(535)	146			715 (727)	573	492 (485)	0		
	Fundan	V_l	1947 (1932)	2064	1639	(1547)	382i			1961 (1969)	2066	1776	(1747)	338i			1952	(1976)	2047	1794	(1787)	2521			1952 (1983)	2041	1842 (1853)	0		
	Energy	T_e	ı	13697	93699	77077	27693	26304	49875	ı	11992	21021		26915	26795	36043	ı		11711	20177		26646	26650	31436	1	11021	18635	26476	26476	26546
	deg)	$\Theta_{ m HSiX}$	96.5 (97.0)	115.4	117.5	(114.4)	88.3	180	180	95.4 (95.0)	115.6	117.8	(116.5)	87.1	180	180	94.5	(93.4)	115.9	117.9	(116.4)	83.7	180	180	93.3 (92.4)	116.5	117.7	180	180	180
	Geometry (Å, deg)	L SiH	1.527 (1.548)	1.489	1.528	(1.557)	2.340	10	1.521	1.518 (1.521)	1.483	1.509	(1.505)	2.458	10	1.522	1.517	(1.518)	1.485	1.509	(1.497)	2.589	10	1.522	1.517 (1.534)	1.487	1.507	10	10	1.521
	Geon	fSiX	$\begin{vmatrix} 1.622 \\ (1.606) \end{vmatrix}$	1.618			1.623	1.609	10	2.078 (2.073)	2.049	2.051	(2.047)	2.075	2.068	10		_	2.214		_	2.242	2.233	10	2.477 (2.463)	2.432	2.441 (2.436)	+	2.455	10
	State		$ ilde{X}$	ã	Ã	V	$ ilde{A}_{TS}$			$\tilde{\chi}$	ã			$ ilde{A}_{TS}$			$ ilde{X}$		ã	Ã	; ,	A_{TS}			\tilde{X}	ã	Ã	$\tilde{A}_{Tc}{}^{a}$		
	Molecule		HSiF					SiF+H	SiH+F	HSiCl					SiCl+H	SiH+Cl	HSiBr						SiBr+H	SiH+Br	HSil				SiI+H	SiH+I

the SiI+H limit is reported.

 b Assumed equal to v_{3} of the \tilde{A} state. This value is used to estimate ZPE.

Table III. Spectroscopic parameters for the \widetilde{X} , \widetilde{a} and \widetilde{A} states of HGeX, and DGeX (X = F, Cl, Br, I). Experimental data (in parentheses) from refs. 9-12.

See the text for other details.

П	ſ	k .d					1	ı		1		1				Т	_		1	- 1	-					l				
perties	$\mathrm{Max}\ \nu_2'$	DGeX			1 a						6 (4)							8	(4)							14	(2)			
sion Pro	Ma	HGeX			$\frac{1}{a}$						3 (2)							5	(3)							6	(2)	1		
Predicted Emission Properties	nergy 1 ⁻¹)	DGeX			564 a						1950 (1533)							2463	(5817)							3821	(1144)	ı		
Predic	Max Energy (cm ⁻¹)	HGeX			386						1700 (1218)							2201	(1/7/)							3528	(1811)			
	Energy	T_{θ}	-	15808	24012	24576			-	14358	21730 (21614)	23680					13926	21064	(20/46)	73527				ı	13104	19507	(19002)	23328		
eX	cm ⁻¹)	1/3	675	663	632	645			390 (398)	389	397 (399)	403			288	(720)	300	279	(6/7)	304			234	(239)	242	214	(205)	214^{d}		
DGeX	Fundamentals (cm ⁻¹)	1/2	536	386	285	160			527 (521)	433	324 (322)	107			502	(490)	388	315	(312)	7.6			474	(473)	369	283	(260)	0		
	Fundan	V_l	1375	1351	192	29 <i>6i</i>			1330 (1320)	1352	1005 (980)	234 <i>i</i>			1313	(1377)	1337	1047	(1048)	1/01			1311	,	1341	1130	(1144)	0		
	Energy (cm ⁻¹)	T_{θ}		15774	23859	24245			-	14340	21634 (21515)	23334			1		13908	20977	(70000)	731/8					13089	19435	(18929)	22963		
Xe	:m ⁻¹)	1/3	627	899	643	645			393 (400)	411	389 (399)	403			289	(167)	301	280	(780)	304			234		243	213	(203)	213^{d}		
HGeX	Fundamentals (cm ⁻¹)	12	792	526	379	219			724 (721)	562	445 (431)	148			669	(094)	536	428	(419)	135			663	(661)	513	386	(337)	0		
	Fundan	V_l	1879	1819	925	402i			1832 (1830)	1850	1324 (1263)	326i			1823	(1022)	1843	1407	(1381)	2351			1825	(1839)	1856	1540	(1542)	0		
	Energy	T_e	-	15885	24382	25473	25165	47843	ı	14384	21950	24565	24467	33753	ı		13957	21264	7007	74394	24430	29786			13130	10670	150/0	24246	24379	25745
		$\Theta_{ m HGeX}$	94.2	116.1	114.6	6.06	180	180	93.8 (95.3)	114.5	115.0	84.9	180	180	93.5	(94.1)	114.9	115.2	(116.3)	21.5	180	180	92.5	(93.5)	115.5	114.6	(116.2)	81.5	180	180
	Geometry	ГGеН	1.604	1.558	1.640	2.162	10	1.599	1.599 (1.594)	1.557	1.608	2.325	10	1.598	1.597	(0.10)	1.559	1.604	(1.613)	2.533	10	1.598	1.596	(1.593)	1.560	1.596	(1.618)	2.806	10	1.599
		$\mathbf{r}_{\mathrm{GeX}}$	1.764	1.753	1.759	1.767	1.765	10	2.193 (2.176)	2.156	2.166 (2.146)	2.190	2.181	10	2.346	(2.320)	2.307	2.324	(2.308)	2.333	2.325	10	2.565	(2.525)	2.517	2.544	(2.515)	2.558	2.529	10
	State		\tilde{X}	\tilde{a}	Ã	$ ilde{A}_{TS}$			Ã	ã	Ã	$ ilde{A}_{TS}$			\tilde{X}		\tilde{a}	Ã		A_{TS}			ũ	Κ	\tilde{a}	Ãb	A	$ ilde{A}_{TS}^c$		
	Molecule		HGeF				GeF+H	GeH+F	HGeCl				GeCl+H	GeH+Cl	HGeBr						GeBr+H	GeH+Br	10011	HGE					GeI+H	GeH+I

^a No fluorescence detected

minimum (218 cm⁻¹ above the main minimum of \tilde{A}). The transition state connecting the secondary minimum to the main minimum is at r_{Gel} =2.628 \mathring{A} , r_{GeH} =1.646 \mathring{A} , ^b A secondary minimum at r_{Gel}=2.712 Å, r_{GeH}=1.719 Å, Θ_{HGel} =57.9° was found. The energy of the secondary minimum is at 19896 cm⁻¹ above the ground state Θ_{HGel} =82.9°, with energy T_e =20523 cm⁻¹ above the ground state (845 cm⁻¹ above the main minimum of \tilde{A})

^c Very shallow transition state. The harmonic frequencies were not calculated.

 $^{\it d}$. Assumed equal to ν_3 of the $\tilde{\it A}$ state. This value is used to estimate ZPE

Table IV. Spectroscopic parameters for the \widetilde{X} , \widetilde{a} and \widetilde{A} states of HSnX, and DSnX (X = F, Cl, Br, I). Experimental data (in parentheses) from ref.

13. See the text for other details.

rties	V2	SnX			0						2 (2)						9						12			_
State Geometry HSnX DSnX DSnX Predicted Emiss Predicted Emiss	HSnX I			0						1 (0)						4						7				
	×			110						645 (458)						1577						2920				
Predict	Geometry HSnX DSnX Predicted Emission Prop	HSnX			-14						466						1366						2668			
		T_{0}	ı	15416	22696	22806				14425	21324 (20831)	21969			0	13990	20584	22161			ı	13233	19287	22207		
Xu		73	594	582	538	899			354 (352)	383	360	390			254	257	238	301			197	199	179	179 ^d		
DS		72	425	306	197	137			448 (426)	324	247 (234)	109			440	320	258	82			430	308	246	0		
		λ_l	1227	1204	529	255i			1220	1189	725	271 <i>i</i>			1206	1185	836	205i			1217	1200	962	0		
	Energy	T_{θ}	1	15385	22529	22515			ı	14400	21198 (20706)	21664			0	13963	20478	21844			1	13207	19203	21871		
Xı	HSnX Fundamentals (cm ⁻¹) Energy	13	533	989	558	695			363 (349)	372	342	390			256	259	246	301			198	199	180	180^{d}		
HSı		72	654	412	250	191			609 (591)	459	349	152			612	441	342	116			601	428	338	0		
		1/1	1664	1624	899	347i			1685 (1665)	1624	918	374 <i>i</i>			1677	1635	1105	286i			1698	1663	1305	0		
E	T_e	ı	15484	23102	23593	23348	42364	ı	14473	21612	22740	22524	34095	ı	14048	20830	22930	22806	30419	ı	13293	19490	23049	67088		
		$\Theta_{ m HSnX}$	92.9	114.9	113.1	91.5	180	180	92.9	112.2	112.2	88.0	180	180	93.1	112.7	113.5	89.4	180	180	92.9	113.5	114.2	180	180	
	State Geometry Fundamentals (cm ⁻¹)	FSnH	1.790	1.746	1.858	2.269	10	1.784	1.794	1.754	1.832	2.359	10	1.785	1.789	1.753	1.816	2.608	10	1.785	1.784	1.752	1.799	10	10	
	-	rSnX	1.962	1.952	1.959	1.967	1.967	10	2.381	2.351	2.364	2.380	2.374	10	2.522	2.494	2.510	2.487	2.488	10	2.739	2.705	2.733	2.686	9896	1
	State r _{SnX}	I	$ ilde{X}$	ã	Ã	$ ilde{A}_{TS}$			\tilde{X}	ã	Ã	$ ilde{A}_{Tc}$			Ž	ã	$v ilde{Y}$	$ ilde{A}_{TS}$			Ž	ã	$ ilde{A}^{\ b}$	$ ilde{A}_{TS}{}^c$		_
		HSnF				SnF+H	SnH+F	HSnCl				SnCl+H	SnH+Cl	HSnBr				SnBr+H	SnH+Br	HSnI				SnI+H	1	

^a A secondary minimum at r_{SnBr}=2.795 Å, r_{SnH}=2.025 Å, Θ_{HSnBr} =39.1° was found. The energy of the secondary minimum is 21923 cm⁻¹ above the ground state (1093 cm⁻¹ above the main minimum of \tilde{A}). No transition state connecting the two minima was found

^b A secondary minimum at r_{Snl}=2.962 Å, r_{SnH}=1.922 Å, Θ_{HSnl} =45.7° was found. The energy of the secondary minimum is 19112 cm⁻¹ above the ground state (378 cm⁻¹ below the main minimum of \tilde{A}). This is actually the global minimum of the \tilde{A} potential energy surface. The transition state connecting the secondary minimum to the main minimum is at $r_{Snl}=2.721$ Å, $r_{SnH}=1.917$ Å, $\Theta_{HSnl}=68.1^{\circ}$, with energy $T_e=21506$ cm⁻¹ above the ground state (2016 cm⁻¹ above the main minimum of \tilde{A}).

^e No barrier was found along the SnI + H dissociation channel for the \tilde{A} state of HSiI. For consistency with the other entries of this Table, the same geometry and energy of the SnI+H limit is reported.

 d Assumed equal to ν_3 of the \tilde{A} state. This value is used to estimate ZPE

$$v_3 = \omega_3 + 2x_{33} + \frac{1}{2}(x_{31} + x_{32}) \tag{4}$$

Anharmonic zero-point vibrational contributions at the minima of the PES's have been calculated with:

$$ZPE = \frac{1}{2}(\omega_1 + \omega_2 + \omega_3) + \frac{1}{4}(x_{11} + x_{22} + x_{33} + x_{12} + x_{12} + x_{23})$$
 (5)

For the transition states, the zero-point vibrational correction has been calculated using only the harmonic frequencies, excluding the imaginary vibrational frequency from the sum. In Tables II-IV only the fundamentals are reported, relegating the harmonic frequencies, anharmonic constants and other spectroscopic quantities to the Supplementary Material.

The calculated fundamentals can be readily compared to experiment since $v_1 = 1_0^1 - 0_0^0$ etc. Similar calculations are reported for the DMX molecules which are usually studied experimentally in tandem with the hydrogenated species. The triplet state theoretical results will be useful in future attempts to detect the laser induced phosphorescence (LIP) spectra.

Combining the *ab initio* electronic energy differences and zero-point energies yielded the calculated T_{θ} values for comparison with experiment as shown in columns 10 (HMX) and 14 (DMX) of the Tables. These T_{θ} values compare favorably with experiment (where data are available), typically 100-200 cm⁻¹ too high for the HSiX molecules and 300-500 cm⁻¹ too high for HGeX. Such systematic deviations may be due both to intrinsic limitations of the electron correlation treatment and to the finite size of the basis sets, in addition to the use of pseudopotentials for Ge atoms (the $\tilde{X} - \tilde{A}$ transitions involve orbitals mainly localized on the central atom). Similar deviations (300 – 500 cm⁻¹) are then expected for Sn-containing molecules

The final four columns of Tables II-IV concern the predicted fluorescence properties of the HMX molecules. Under the Max. Energy heading, we have tabulated the energy difference between the ZPE-corrected energy barrier to dissociation of the \widetilde{A} state and the zero-point energy of the \widetilde{A} state. This quantity provides an upper limit to the energy range of the vibrational levels in the \widetilde{A} state that are below the barrier to dissociation and therefore can potentially fluoresce back down to the ground state. These numbers are different for HMX and

DMX, due to the lower zero-point energy of the DMX species. For the experimental counterpart, we report the vibrational energy of the highest observed level in the LIF spectrum. There are no entries in the triplet state row since the \tilde{a} state potentials have deep wells (see for example, Fig, 2 for HGeF) and would all be expected to phosphoresce if the weak spin-forbidden transitions could be observed and the Franck-Condon factors were favorable.

Transitions to the upper state bending levels predominate in the experimentally observed LIF spectra, a direct consequence of the large increase in the bond angle on electronic excitation. With this in mind, an alternative measure of the extent of the LIF spectrum is to count the number of bands expected in the bending progression (2_0^1 , 2_0^2 , etc.) before the onset of dissociation, which can be readily compared with experiment. These results are presented in the columns labelled Max v_2' , with larger values for DMX again due to the difference in zero-point energies.

It is important to emphasize that both Max Energy and Max v_2' are the calculated *Maximum* energy and v_2' quantum number predicted for the LIF spectrum. There are at least three factors that may be responsible for lowering these values in real experimental results. First, the Franck-Condon factors may mitigate against observing transitions high up in the excited state vibrational manifold. Second, there may be experimental reasons why the observed LIF spectrum is weak such as inefficient laser dyes or poor production of the HMX molecules in our discharge jet, $^{6-12}$ so that the transitions to higher levels were not observed. Third, tunneling through the dissociation barrier may occur, so that our numbers may overestimate the extent of the LIF band system for some HMX species.

D. $\tilde{A}^{I}A''$ state well depths and energy barriers to dissociation

From the energies reported in the T_e column of tables II-IV it is possible to analyze the energy barriers to dissociation of the \widetilde{A} states (without vibrational contribution) as the sum of two terms, each one referred to the MX + H dissociation limit: the depth of the potential energy well and the height of the transition state. These values are plotted in Fig.3. From the figure it is evident that, for each M atom, the depth of the potential well

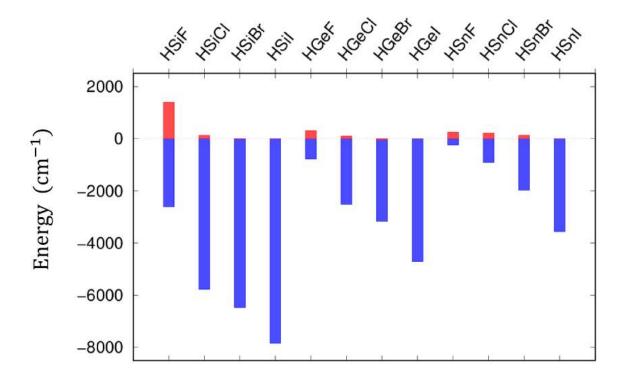


Figure 3. MX + H dissociation energies from the $\tilde{A}^{1}A''$ excited state of HMX. The depth of the bonding well with respect to the dissociation limit is shown in blue, the height of the dissociation barrier above the dissociation limit is in red.

increases regularly from F to I along the halogen series, while for each halogen it decreases smoothly from Si to Sn. On the other hand, the height of the transition state is relevant only for fluorine compounds and, to a much less extent, for chlorine compounds, being essentially zero for the bromine- and iodine-containing molecules.

IV. DISCUSSION

A. Rationale for trends in the \widetilde{A} state well depth and barriers to HMX \rightarrow H + MX dissociation

Our calculations show that some HMX molecules have a significant \widetilde{A} state energy barrier to the H + MX dissociation (see Tables II-IV and Fig. 3) whereas there is no barrier evident in the \widetilde{X} or \widetilde{a} states and the \widetilde{A} state bonding potential wells vary systematically with the identity of the halogen. Here we attempt to rationalize these findings based on the relevant potential energy curves, similar to the approach used in a previous study of the isoelectronic HNO free radical. We start by considering the potential curves for the linear HGeX molecules as a function of the H-Ge bond distance as shown in Fig. 4. It is evident that the major difference among the various species is the behavior of the ${}^{1}\Delta$ state, with high dissociation asymptote for HGeF, becoming progressively lower through HGeCl, HGeBr and HGeI. Similar calculations show that the same trends are found for the HSiX and HSnX molecules.

For linear geometries the ${}^{1}\Sigma^{+}$, the ${}^{3}\Sigma^{-}$ and the ${}^{1}\Delta$ states are strongly bound and correlate asymptotically along the r_{GeH} stretching coordinate with the excited GeF products $H({}^{2}S) + GeF(A^{2}\Sigma^{+})$, $H({}^{2}S) + GeF(a^{4}\Sigma^{-})$ and $H({}^{2}S) + GeF(C^{2}\Delta)$, respectively, whereas the ${}^{1}\Pi$ and ${}^{3}\Pi$ states are either dissociative or weakly bound and correlate with the ground state $H({}^{2}S) + GeF(X^{2}\Pi)$ products. In linear configurations, all these electronic states have different symmetry, so there is no interaction between them (ignoring spin orbit coupling), which leads to curve crossings between all the states.

As the molecule bends, it assumes C_s symmetry and the degeneracies of the electronic states are lifted forming species of A' and A'' symmetry. The doubly degenerate ${}^{1}\Pi$ and ${}^{1}\Delta$ states split into two components, one

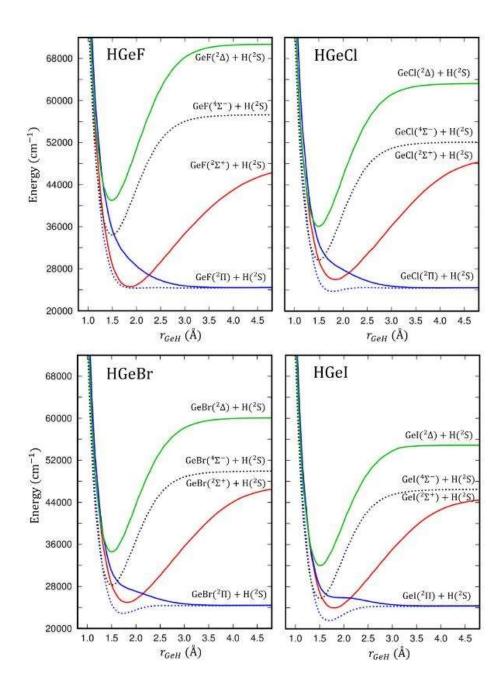


Figure 4. Linear molecule HGeX potential energy curves as a function of GeH bond distance. Singlet states are denoted by solid lines and triplet states by dashed lines. Red lines are Σ^+ states, blue lines Π states, black lines Σ^- states and green lines Δ states.

with ${}^1A'$ and the other with ${}^1A''$ symmetry, as shown by the correlation diagram in Fig. 5. The strongly bound ${}^1\Sigma^+({}^1A')$ and ${}^1\Delta$ (${}^1A'$) states mix with the repulsive ${}^1\Pi$ (${}^1A'$) state to form the bound \tilde{X}^1A' state. Similarly, the strongly bound ${}^3\Sigma^-({}^3A'')$ state mixes with the weakly bound ${}^3\Pi$ (${}^3A''$) state to form the bound $\tilde{\alpha}^3A''$ state. In both the \tilde{X}^1A' and $\tilde{\alpha}^3A''$ states, the attractive Σ (and Δ) character prevails over the repulsive Π character at all geometries, eliminating any barrier to dissociation for all HMX molecules.

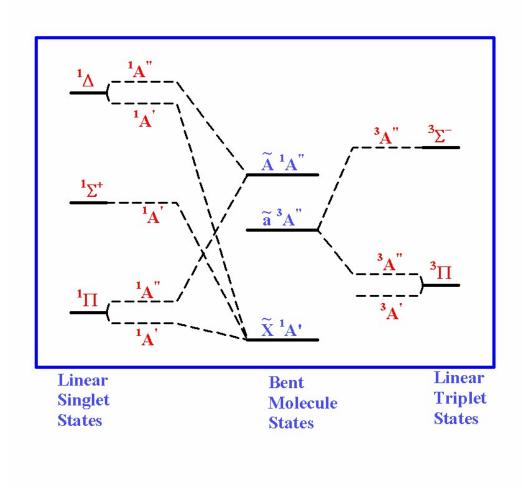


Figure 5. Correlation diagram of the linear HMX molecule singlet and triplet states with the bent molecule states. The higher energy bent molecule ³A' states are not shown.

The situation is more complicated for the $\widetilde{A}^I A''$ state, which is formed by the mixing of the ${}^I A''$ components of the ${}^1 \Delta$ and ${}^1 \Pi$ states on bending. The attractive nature of this state at intermediate values of r_{GeH} reflects the dominant ${}^1 \Delta$ character, with a switch to the repulsive ${}^1 \Pi$ character at large r_{GeH} values. The depth of the bonding well and the height of any barrier to dissociation in the $\widetilde{A}^I A''$ state is then governed by a delicate balance between the opposing effects of the depth of the ${}^1 \Delta$ attractive well and the repulsive nature of the ${}^1 \Pi$ state. For the fluorinated molecules (HMF), the ${}^1 \Delta$ lies at higher energies (compared to other halogens) and the ${}^1 \Pi$ state contribution dominates, yielding a significant barrier to dissociation and a small bonding well. Progressing through the halogens, the ${}^1 \Delta$ state lowers and gets closer to the ${}^1 \Pi$ state becoming increasingly dominant, so the \widetilde{A} state bonding depth increases and overwhelms the barrier to dissociation (see Fig. 3).

In other words, the shape of the \widetilde{A} state potential is the result of a strong avoided crossing between the A'' component of the repulsive ${}^{1}\Pi$ ground state and the A'' component of the attractive ${}^{1}\Delta$ excited state. If the interaction (occurring only at bent geometries) between these states is weak, the \widetilde{A} state remains essentially dissociative (HSnF, for example). If it is strong, the state became fully attractive and the barrier eventually disappears (contrast HSnI with HSnF in Fig. 3).

B. The $\tilde{X}^I A'$ ground states

All of the HSiX ground state species have been characterized spectroscopically and our theoretical results are in good agreement with experiment. A careful study of Table II shows maximum deviations (|obs. – calc.|) in bond lengths of 0.021 Å (HSiF), bond angles of 1.1 ° (HSiBr) and vibrational fundamentals of 41 cm⁻¹ (DSiI). For HGeX, the HGeF species has not been observed experimentally, although the others have been studied by LIF and wavelength resolved emission studies. Table III shows maximum deviations (|obs. – calc.|) in bond lengths of 0.04 Å (HGeI), bond angles of 1.5 ° (HGeCl) and vibrational fundamentals of 14 cm⁻¹ (HGeI). HSnCl is the only HSnX species currently known experimentally and the maximum deviation in the ground state

fundamentals (Table IV) is 20 cm⁻¹. The trends indicate that our theoretical values for the experimentally unknown HMX ground state quantities should be similarly reliable.

C. The $\tilde{a}^{3}A''$ states

None of the triplet states of the HMX species have been observed experimentally so the values in Tables II – IV provide predictions for future studies. All the triplet states have deep bonding wells supporting a broad range of vibrational levels, no barrier to the H + MX dissociation, and a large bond angle relative to the ground state. The HSiX \tilde{a} - \tilde{X} transitions are quite low in energy [T_0 = 732 nm (HSiF) to 908 nm (HSiI)] and are liable to be quite weak, making them difficult to detect. The progression to HGeX and HSnX shifts the \tilde{a} - \tilde{X} transitions $1000 - 2000 \text{ cm}^{-1}$ to higher energy and the increase in spin-orbit coupling should make the triplet-singlet transitions more intense. The large change in bond angle indicates that long Franck-Condon active progressions in the bending mode would be expected in LIP spectra accompanied by a significant increase in the A rotational constant on excitation.

D. Fluorescence properties of the HMX $\tilde{A}^{1}A^{"}$ states

The main results obtained from this systematic study of HMX compounds concern the fluorescence properties of the \widetilde{A} states and predictions of whether and/or to what extent the individual species can be detected by LIF spectroscopy. We discuss each molecule individually.

HSiF. The \tilde{A} state has quite a high barrier to dissociation (\approx 1400 cm⁻¹, the highest within the molecules considered here) and a well-developed bonding potential well (\approx -2600 cm⁻¹). The predicted emission properties match experiment very well, both for the fluorescence energy interval and for the number of observable bending levels. For both isotopologues, the experimental LIF spectrum stops about 500 cm⁻¹ below the theoretical maximum. The calculated HSiF absorption spectrum⁵⁰ shows that the major 2_0^n progression peaks at 2_0^2 and becomes very weak beyond 2_0^4 or 2_0^5 , depending on the level of theory, in good agreement with experiment and the present theoretical predictions.

HSiCl. With respect to HSiF, the barrier to dissociation is drastically lowered to 120 cm⁻¹ but the bonding well depth is approximately doubled. This leads to a near-doubling of the fluorescence energy interval and of the bending levels within this interval, although the experimental results stop well short of these theoretical maxima. The calculated absorption spectra¹⁶ of HSiCl and DSiCl show that the Franck-Condon activity fades away about 4000 cm^{-1} above the 0-0 band, with Max $v_2' = 4$ for HSiCl and 10 for DSiCl, in excellent accord with experiment. It is evident that with the increased well-depth, the extent of the observed LIF spectrum is Franck-Condon rather than dissociation limited.

HSiBr. For this species the dissociation barrier becomes negligible but the bonding well depth is further lowered to $\approx 6500 \text{ cm}^{-1}$ below the SiBr + H dissociation limit. Theory predicts that up to 10 (15) bending levels might be observed for HSiBr (DSiBr), but experimental observations stop at about half of the theoretical maximum number, again due to the lack of Franck-Condon activity.

HSil. No barrier to dissociation was found and the bonding well is $\approx 7800 \text{ cm}^{-1}$, the deepest of the whole HMX series. In spite of this, the number of observed bending levels is only about half of that predicted theoretically, a consequence of at least two mitigating factors. First, Franck-Condon considerations probably limit the observable extent of the LIF spectrum to $3000 - 4000 \text{ cm}^{-1}$. Second, the observed LIF spectra of HSiI and HGeI are characterized as weak^{7,12} so they may not span the full range of bands. In our experiments, these species were synthesized by subjecting H₃MI vapor to a rather violent electric discharge at the exit of a supersonic expansion and it may be that the M–I bond does not stand up well to such abuse. In addition, the energies of the dissociation channels SiI + H and SiH + I are calculated to be very similar, so the opening of a second dissociation channel may influence the extent of the LIF spectrum.

HGeF. Both the barrier to dissociation and the bonding well are very small so, theoretically, only the 000 and the 010 vibrational levels are likely to exist for both isotopologues. This restriction suggests that either the LIF spectrum will not be observable or it will consist of no more that one or two bands which might fluoresce at energies low enough to preclude the formation of the GeF + H dissociation products. We have previously reported

unsuccessful attempts to observe the HGeF LIF spectrum using a H₃GeF precursor and by the reaction of germane with fluorine.⁹

HGeCl. In HGeCl, the barrier to dissociation is only $\approx 100 \text{ cm}^{-1}$, but the bonding well is $\approx 2500 \text{ cm}^{-1}$, sufficient to support several bending levels for both isotopologues. The experimental LIF spectra are in accord with the theoretical predictions, but tend to lose intensity $400 - 500 \text{ cm}^{-1}$ below the dissociation barrier. Franck-Condon profiles of the absorption spectra, calculated in the harmonic approximation, ¹⁷ are in good agreement with the LIF data, indicating that the intensity tails off due to a diminution of vibrational overlap rather than the abrupt opening of a dissociation channel.

HGeBr. HGeBr has no significant barrier to dissociation and a bonding potential well of $\approx 3100 \text{ cm}^{-1}$, slightly larger than that of HGeCl. This prediction is reflected in the LIF spectra which extend $500 - 600 \text{ cm}^{-1}$ further in HGeBr/DGeBr compared to HGeCl/DGeCl. Harmonic Franck-Condon calculations by Lin *et al.*^{18,19} on both pairs of molecules show exactly this type of behavior, with the bending progression terminating after 2_0^3 in the hydrogen compounds and after 2_0^4 for the deuterated species, in accord with experiment. In HGeBr/DGeBr, it is again clear that the LIF spectra lose Franck-Condon intensity prior to the onset of dissociation.

HGeI. The potential energy surface of the \tilde{A} $^{1}A''$ state has a deep bonding well of $\approx 3500 \text{ cm}^{-1}$, with a negligible barrier to dissociation. This property should in principle lead to an extensive absorption spectrum, but the experimental fact is that the LIF spectrum is not very lengthy (1800 cm⁻¹). As in the case of HSiI, this difference is probably due to the difficulty in producing HGeI in a discharge and the tailing off of the Franck-Condon profile well before the dissociation limit. In this case, we find the extra complication that the bending curve presents a swallow secondary minimum at $\theta_{HGeI} \sim 60^{\circ}$ (see Supplementary Material). The transition state reported in Table III connects the two minima along the bending coordinate and its energy is only $\approx 850 \text{ cm}^{-1}$ above the main minimum of the \tilde{A} $^{1}A''$ surface. In addition, the dissociation limits to GeI + H (24379 cm⁻¹) and GeH + I (25745 cm⁻¹) are energetically very similar, a feature found for all the HMI (M = Si, Ge, Sn) species (see Tables I - IV).

Despite these difficulties, the calculations clearly indicate that HGeI and DGeI should fluoresce and this prediction agrees with experiment.

HSnF. The \tilde{A} $^{1}A''$ state of this molecule has both a barrier to dissociation and a bonding well smaller than 250 cm⁻¹, too limited to give rise to any bonded or quasi-bonded state. In Table IV, the predicted Max Energy for HSnF is negative, meaning that the zero-point energy is higher than the lowest vibrational level of the transition state. For DSnF, the zero-point level lies at slightly lower energies, but still very close to the transition state. These results lead to the firm prediction that HSnF and DSnF should not be observable by LIF spectroscopy. If the HSnF/DSnF molecules can be made in the gas phase, they will simply dissociate into hydrogen (deuterium) atoms and SnF molecules on excitation to the \tilde{A} state, which should occur around 22 000 cm⁻¹.

HSnCl. Our calculations predict that only the 0-0 and possibly 2_0^1 bands of HSnCl and the 0-0, 2_0^1 and 2_0^2 bands of DSnCl should be observable in the bending progressions prior to the onset of molecular dissociation and an abrupt breaking off of the fluorescence. In recent experiments in the laboratory at Ideal Vacuum Products this is precisely what is observed, ¹³ with a single intense 0-0 band in the LIF spectrum of HSnCl, which exhibits a very short fluorescence lifetime, indicative of the near onset of dissociation. In DSnCl, the bending progression extends to 2_0^2 , with decreasing fluorescence lifetimes up the vibrational manifold and loss of fluorescence at 458 cm⁻¹ above the 0-0 level. The calculations give reliable values for the vibrational fundamentals in the ground and \widetilde{A} excited states (where known, see Table IV) and only slightly overestimate T_0 by 2.4% for both HSnCl and DSnCl. It is gratifying that the present theoretical results predict the extent of the LIF spectra and the effects of deuteration so well, lending confidence in the predictions for other as yet undetected HMX species.

HSnBr. The HSnBr/DSnBr species have deeper \tilde{A} state bonding wells that the chloro--compounds and negligible dissociation energy barriers. This immediately leads to the prediction that the brominated species should have more extensive LIF spectra, ranging 1300 - 1500 cm⁻¹ above the 0-0 band. It is likely that dissociation and loss of vibrational overlap intensity will be competitive factors in determining the observed extent of such spectra.

We note that a secondary minimum at a small bending angle was found, but it is at an energy larger than the SnBr + H dissociation and so it should not affect the LIF spectra.

HSnI. HSnI and DSnI are predicted to have significant bonding potential energy wells in the \widetilde{A} state without dissociation energy barriers, which would suggest that LIF spectra could be observed. However, in monoiodostannylene, we find similar but even more complexities in the potential energy surfaces than we found for HGeI. In addition to the large angle \widetilde{A} state minimum at 114°, there is a second small angle minimum at 46° which in this case is actually the global \widetilde{A} state minimum (378 cm⁻¹ below the large angle minimum). The two competing dissociation channels are also energetically similar (SnI + H = 23 049 cm⁻¹ and SnH + I = 24 957 cm⁻¹). Due to these difficulties, it has proven unrealistic to predict whether LIF spectra of HSnI or DSnI are likely to be observable

V. CONCLUSIONS

The main conclusion of this work is that whether or not the $\tilde{A}^{I}A^{"}$ states of the HMX molecules fluoresce is determined primarily by the location of the excited state H (2 S) + MX (X 2 \Pi) dissociation limit. The depth of the excited state potential energy bonding well and the existence of a barrier to dissociation (if any) can be rationalized as due to the extent of the mixing of the A" components of the $^{1}\Delta$ and $^{1}\Pi$ states of the linear molecule configuration on bending.

A simple model based on perturbative second order theory proved to be sufficient to successfully explain the main features of the \widetilde{A} - \widetilde{X} electronic transition of the HMX/DMX (M=Si,Ge, X=F,Cl,Br) triatomics and reproduce their known spectroscopic constants. Such a model weakens for the iodine-containing species, for which the agreement is less satisfactory. This success supports a reliable prediction of the same spectroscopic properties for the corresponding tin-containing species.

Our calculations show that HGeF and DGeF dissociate very low down in the first excited singlet state and are unlikely to be detectable by LIF spectroscopy. The extent of the observable LIF spectra of the other HSiX and HGeX molecules is shown to be controlled as much by the slow diminution of the Franck-Condon factors as it is by the onset of HMX \rightarrow H + MX dissociation channel. In the HSnX species, HSnF and DSnF are clearly dissociative and unlikely to fluoresce. In very good agreement with experiment, HSnCl is predicted to have a very limited LIF spectrum, which should be somewhat more extensive in DSnCl before the onset of dissociation. The calculations predict a deeper excited state bonding well for HSnBr/DSnBr and a more extensive LIF spectrum. Although the excited state potential energy well is even deeper for HSnI/DSnI, the ab initio results are complicated by a small angle global minimum and the opening of both H + SnI and HSn + I dissociation channels at similar energies. These difficulties make it impossible to make a definitive prediction as to whether the LIF spectra of HSnI and DSnI are likely to be observable, assuming that the iodo species can be made at all. Simple second order perturbation theory, which proved to be successful for the prediction of the spectroscopic behavior of most HMX species, is clearly not adequate for HMI species due to the complex shape of their first singlet excited state potential energy surface. For these latter, a more complex and computationally demanding variational approach will be mandatory. Finally, the yet unobserved triplet-singlet phosphorescence spectra of all the HMX molecules are calculated to occur in the 11000-16000 cm⁻¹ range and are likely to be progressively stronger and perhaps observable with standard techniques for the germanium and tin species.

SUPPLEMENTARY MATERIAL:

See the Supplementary Material for (I) Frontier orbitals plots for all 12 HMX species, (II) Potential energy curves for the lowest states for all 12 HMX species and (III) Calculated spectroscopic parameters for HMX and DMX main isotopologues

AUTHOR'S CONTRIBUTIONS:

All authors contributed equally to this work.

ACKNOWLEDGEMENTS

The authors are grateful to Tony Smith of Ideal Vacuum Products, LLC for his continuing interest, encouragement, and financial support during the course of this research project. R.T. acknowledges financial support from the University of Bologna, and the from Italian MIUR (PRIN 2017, PHANTOMS project, Prot. 2017A4XRCA).

CONFLICTS OF INTEREST:

The authors have no conflicts to disclose.

DATA AVAILABILITY

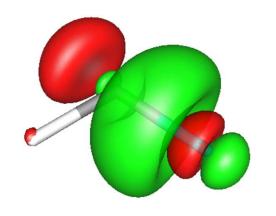
The data that support the findings of this study are available within the article and in the supplementary material.

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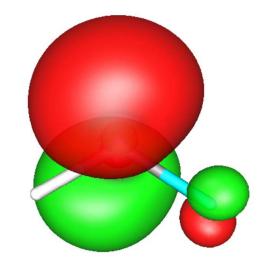
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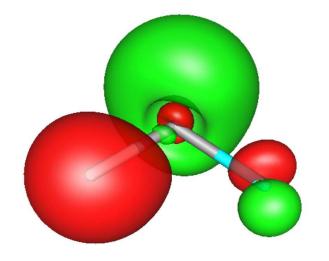
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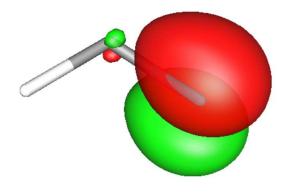
a′_{LUMO+1}



 $a^{\prime\prime}_{\text{LUMO}}$



 a'_{HOMO}



a"_{HOMO-1}

